

DDTD122TU-7-F Datasheet



<https://www.DiGi-Electronics.com>

DiGi Electronics Part Number	DDTD122TU-7-F-DG
Manufacturer	Diodes Incorporated
Manufacturer Product Number	DDTD122TU-7-F
Description	TRANS PREBIAS NPN 50V SOT323
Detailed Description	Pre-Biased Bipolar Transistor (BJT) NPN - Pre-Biased 50 V 500 mA 200 MHz 200 mW Surface Mount SOT-323



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DiGi is a global authorized distributor of electronic components.

Purchase and inquiry

Manufacturer Product Number:

DDTD122TU-7-F

Series:

-

Transistor Type:

NPN - Pre-Biased

Voltage - Collector Emitter Breakdown (Max):

50 V

DC Current Gain (hFE) (Min) @ Ic, Vce:

100 @ 5mA, 5V

Current - Collector Cutoff (Max):

500nA (ICBO)

Power - Max:

200 mW

Package / Case:

SC-70, SOT-323

Base Product Number:

DDTD122

Manufacturer:

Diodes Incorporated

Product Status:

Obsolete

Current - Collector (Ic) (Max):

500 mA

Resistor - Base (R1):

220 Ohms

Vce Saturation (Max) @ Ib, Ic:

300mV @ 2.5mA, 50mA

Frequency - Transition:

200 MHz

Mounting Type:

Surface Mount

Supplier Device Package:

SOT-323

Environmental & Export classification

RoHS Status:

ROHS3 Compliant

REACH Status:

REACH Unaffected

HTSUS:

8541.21.0075

Moisture Sensitivity Level (MSL):

1 (Unlimited)

ECCN:

EAR99

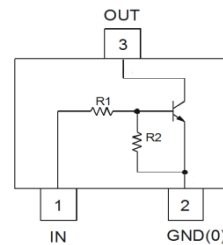
Features

- Complementary PNP Types Available (DDTB)
- Built-In Biasing Resistors
- Surface Mount Package Suited for Automated Assembly
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- Halogen and Antimony Free. "Green" Device (Note 3)**
- For automotive applications requiring specific change control (i.e.: parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please refer to the related automotive grade (Q-suffix) part. A listing can be found at <https://www.diodes.com/products/automotive/automotive-products/>.**
- This part is qualified to JEDEC standards (as references in AEC-Q) for High Reliability. <https://www.diodes.com/quality/product-definitions/>**

Part Number	R1(NOM)	R2(NOM)
DDTD122LU	0.22k Ω	10k Ω
DDTD142JU	0.47k Ω	10k Ω
DDTD122TU	0.22k Ω	Open
DDTD142TU	0.47k Ω	Open



Top View



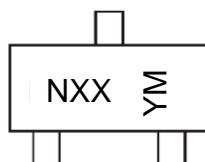
Device Schematic

Ordering Information (Note 4)

Part Number	Status	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
DDTD122LU-7-F	Obsolete	Standard	N75	7	8	3,000
DDTD142JU-7-F	Active	Standard	N76	7	8	3,000
DDTD122TU-7-F	Obsolete	Standard	N77	7	8	3,000
DDTD142TU-7-F	Obsolete	Standard	N78	7	8	3,000

- Notes:
- No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
 - See <https://www.diodes.com/quality/lead-free/> for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
 - Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
 - For packaging details, go to our website at <https://www.diodes.com/design/support/packaging/diodes-packaging/>.

Marking Information



NXX = Product Type Marking Code
 YM = Date Code Marking
 Y = Year (ex: I = 2021)
 M = Month (ex: 9 = September)

Date Code Key

Year	2010	...	2021	2022	2023	2024	2025	2026	2027	2028	2029	2030
Code	X	...	I	J	K	L	M	N	O	P	R	S

Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	O	N	D



DDTD (LO-R1) U

Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

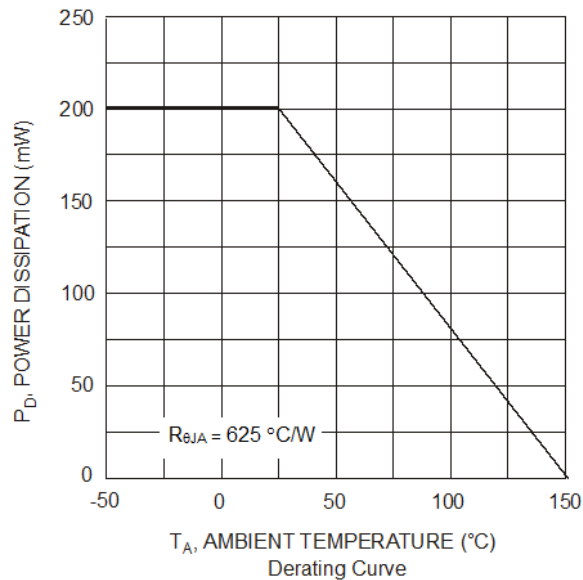
Characteristic		Symbol	Value	Unit
Supply Voltage, (3) to (2)		V _{CC}	50	V
Input Voltage, (1) to (2)	DDTD122TU DDTD142TU	V _{IN}	-5 to +6 -5 to +6	V
Input Voltage, (2) to (1)	DDTD122TU DDTD142TU	V _{EBO(MAX)}	5	V
Output Current	All	I _C	500	mA

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	P _D	200	mW
Thermal Resistance, Junction to Ambient Air (Note 5)	R _{θJA}	625	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

Note: 5. Mounted on FR4 PC Board with minimum recommended pad layout.

Power Derating Curve





DDTD (LO-R1) U

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.) **R1 & R2 Types**

Characteristic		Symbol	Min	Typ	Max	Unit	Test Condition
Input Voltage	DDTD122LU DDTD142JU	V _{I(off)}	0.3 0.3	—	—	V	V _{CC} = 5V, I _O = 100μA
	DDTD122LU DDTD142JU	V _{I(on)}	—	—	2.0 2.0	V	V _O = 0.3V, I _O = 20mA V _O = 0.3V, I _O = 20mA
Output Voltage		V _{O(on)}	—	—	0.3	V	I _O /I _I = 50mA/2.5mA
Input Current	DDTD122LU DDTD142JU	I _I	—	—	28 13	mA	V _I = 5V
Output Current		I _{O(off)}	—	—	0.5	μA	V _{CC} = 50V, V _I = 0V
DC Current Gain	DDTD122LU DDTD142JU	G _I	56 56	—	—	—	V _O = 5V, I _O = 50mA
Gain-Bandwidth Product (Note 6)		f _T	—	200	—	MHz	V _{CE} = 10V, I _E = 5mA, f = 100MHz

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.) **R1-Only Types**

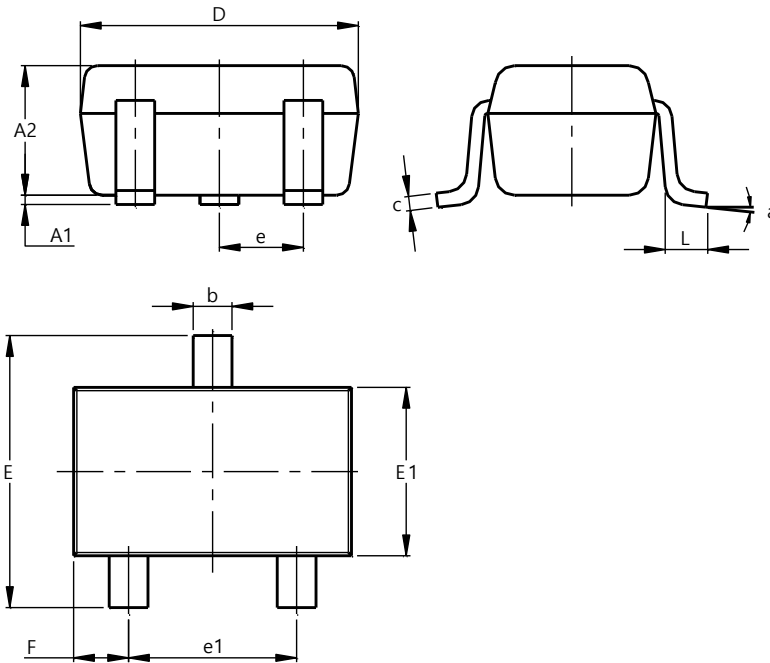
Characteristic		Symbol	Min	Typ	Max	Unit	Test Condition
Collector-Base Breakdown Voltage		BV _{CBO}	50	—	—	V	I _C = 50μA
Collector-Emitter Breakdown Voltage		BV _{CEO}	40	—	—	V	I _C = 1mA
Emitter-Base Breakdown Voltage	DDTD122TU DDTD142TU	BV _{EBO}	5	—	—	V	I _E = 50μA I _E = 50μA
Collector Cutoff Current		I _{CBO}	—	—	0.5	μA	V _{CB} = 50V
Emitter Cutoff Current	DDTD122TU DDTD142TU	I _{EBO}	— —	— —	0.5 0.5	μA	V _{EB} = 4V
Collector-Emitter Saturation Voltage		V _{CE(sat)}	—	—	0.3	V	I _C = 50mA, I _B = 2.5mA
DC Current Transfer Ratio	DDTD122TU DDTD142TU	h _{FE}	100 100	250 250	600 600	—	I _C = 5mA, V _{CE} = 5V
Gain-Bandwidth Product (Note 6)		f _T	—	200	—	MHz	V _{CE} = 10V, I _E = 5mA, f = 100MHz

Note: 6. Transistor - for reference only.

Package Outline Dimensions

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

SOT323

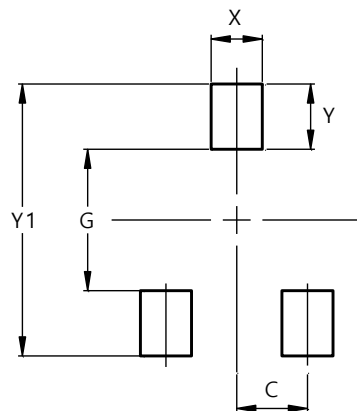


SOT323			
Dim	Min	Max	Typ
A1	0.00	0.10	0.05
A2	0.90	1.00	0.95
b	0.25	0.40	0.30
c	0.10	0.18	0.11
D	1.80	2.20	2.15
E	2.00	2.20	2.10
E1	1.15	1.35	1.30
e	0.650 BSC		
e1	1.20	1.40	1.30
F	0.375	0.475	0.425
L	0.25	0.40	0.30
a	0°	8°	--
All Dimensions in mm			

Suggested Pad Layout

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

SOT323



Dimensions	Value (in mm)
C	0.650
G	1.300
X	0.470
Y	0.600
Y1	2.500

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